

Features

- $BV_{CEO} > 50V$
- $I_C = 4A$ Continuous Collector Current
- Low Saturation Voltage (100mV max @1A)
- $R_{SAT} = 68m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} Specified up to 6A for High Current Gain Hold Up
- Low Profile 0.6mm High Package for Thin Applications
- $R_{\theta JA}$ Efficient, 60% Lower than SOT23
- 4mm² Footprint, 50% Smaller than SOT23
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>**

Mechanical Data

- Package: U-DFN2020-3
- Nominal Package Height: 0.6mm
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu, Solderable per MIL-STD-202, Method 208
- Weight: 0.01 grams (Approximate)

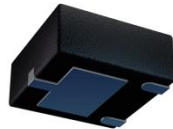
Applications

- MOSFET gate driving
- DC-DC converters
- Charging circuits
- Motor controls
- Power switches

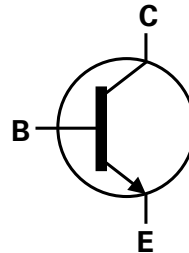
U-DFN2020-3 (Type B)



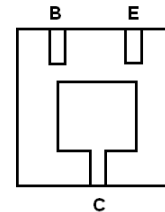
Top View



Bottom View



Device Symbol



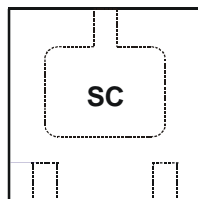
Bottom View
Pin-Out

Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
ZXTN619MATA	U-DFN2020-3 (Type B)	SC	7	8	3,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



Top View

SC = Product Type Marking code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V _{CB0}	100	V
Collector-Emitter Voltage		V _{CEO}	50	
Emitter-Base Voltage		V _{EBO}	7	
Peak Pulse Current		I _{CM}	6	A
Continuous Collector Current	(Note 5)	I _C	4	
	(Note 6)		4.3	
Base Current		I _B	1	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P _D	1.5	W
	Linear Derating Factor		(Note 6)	
			19.6	mW/°C
Thermal Resistance, Junction to Ambient	(Note 5)	R _{θJA}	83	°C/W
	(Note 6)		51	
Thermal Resistance, Junction to Lead	(Note 7)	R _{θJL}	16.8	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	C
Electrostatic Discharge – Charged Device Model	ESD CDM	1,000	V	IV

- Notes:
5. For a device mounted with the exposed collector pad on 31mm × 31mm (10cm²) 1oz copper that is on a single sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state. The entire exposed collector pad is attached to the heatsink.
 6. Same as Note 5, except the device is measured at t ≤ 5s.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JESD22-A114, JESD22-A115 & JESD22-C101.

Thermal Characteristics and Derating Information

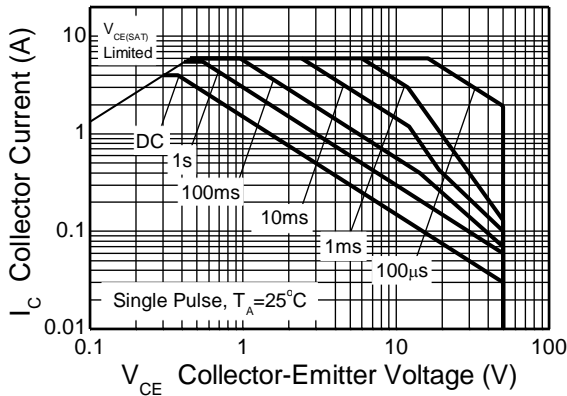


Figure 1. Safe Operating Area

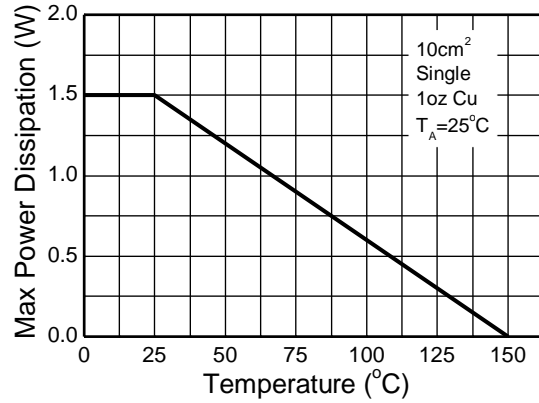


Figure 2. Derating Curve

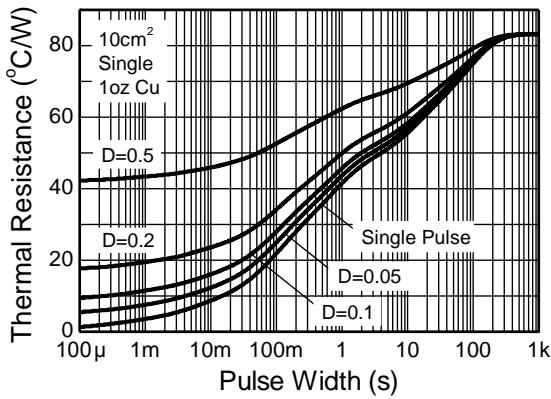


Figure 3. Transient Thermal Impedance

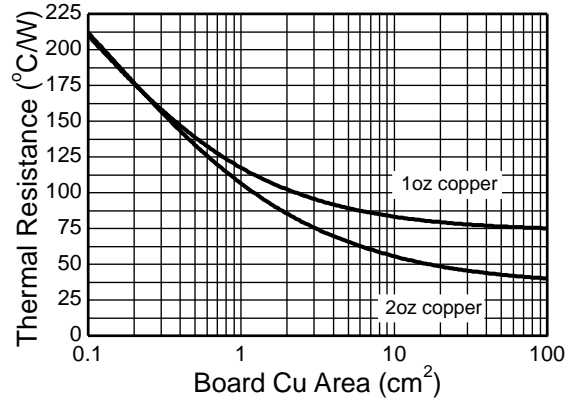


Figure 4. Thermal Resistance v Board Area

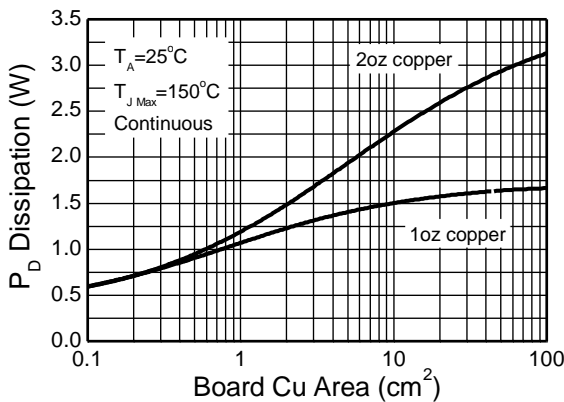


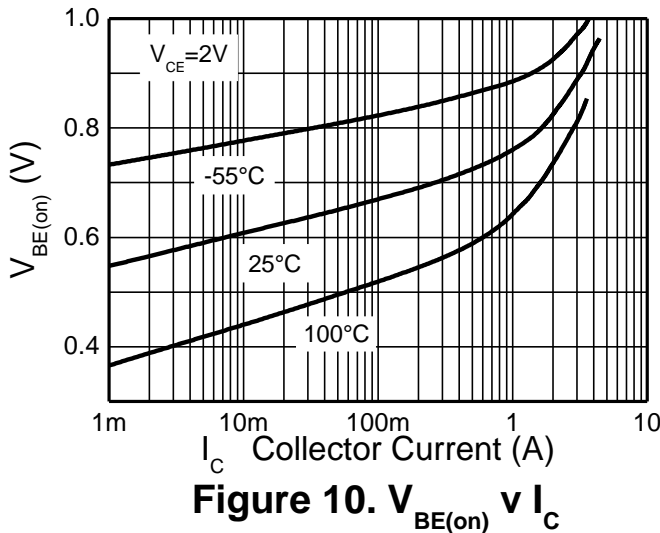
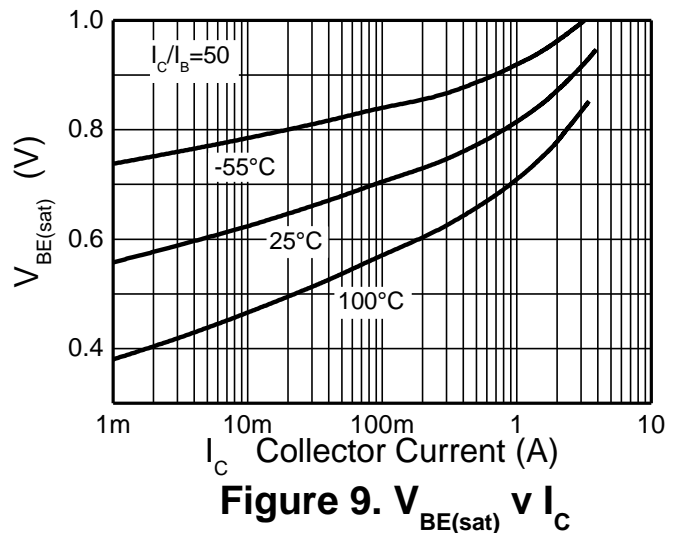
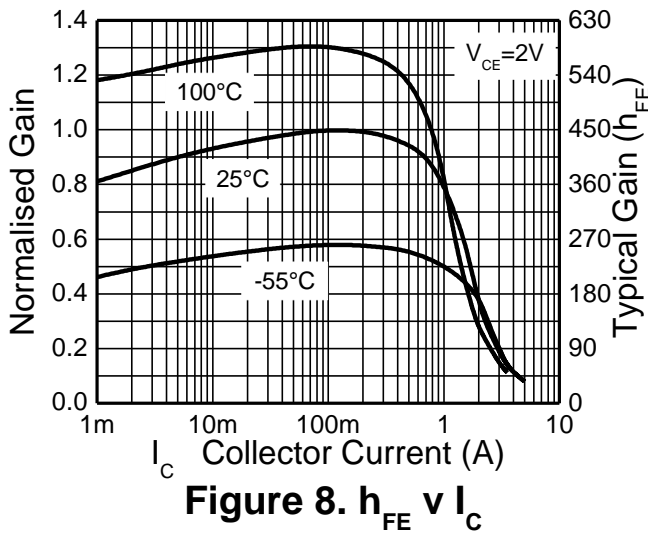
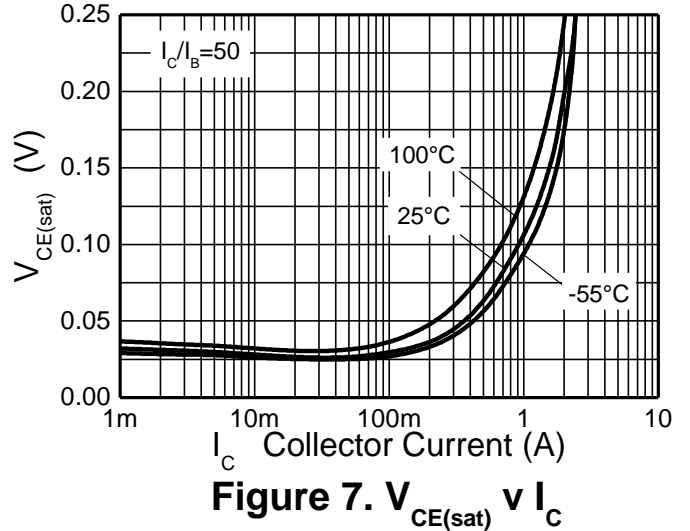
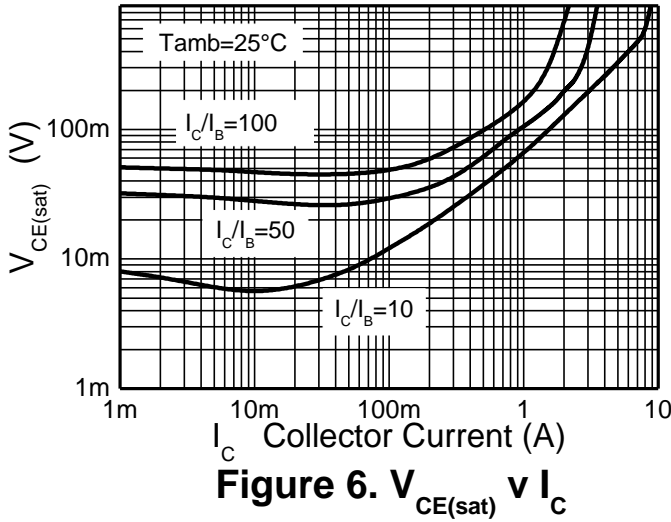
Figure 5. Power Dissipation v Board Area

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CB0}	100	190	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	50	65	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.2	—	V	I _E = 100μA
Collector Cutoff Current	I _{CB0}	—	—	100	nA	V _{CB} = 80V
Emitter Cutoff Current	I _{EBO}	—	—	20	nA	V _{EB} = 6V
Collector Emitter Cutoff Current	I _{CES}	—	—	100	nA	V _{CES} = 40V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	200	400	—	—	I _C = 10mA, V _{CE} = 2V
		300	450	—		I _C = 200mA, V _{CE} = 2V
		200	400	—		I _C = 1A, V _{CE} = 2V
		100	225	—		I _C = 2A, V _{CE} = 2V
		—	40	—		I _C = 6A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	10	20	mV	I _C = 0.1A, I _B = 10mA
		—	70	100		I _C = 1A, I _B = 50mA
		—	145	200		I _C = 1A, I _B = 10mA
		—	150	220		I _C = 2A, I _B = 50mA
		—	225	300		I _C = 3A, I _B = 100mA
		—	270	320		I _C = 4A, I _B = 200mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	0.94	1.00	V	I _C = 4A, V _{CE} = 2V
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	1.00	1.07	V	I _C = 4A, I _B = 200mA
Output Capacitance	C _{OBO}	—	12	20	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	100	165	—	MHz	V _{CE} = 10V, I _C = 50mA f = 100MHz
Turn-On Time	t _{on}	—	170	—	ns	V _{CC} = 10V, I _C = 1A
Turn-Off Time	t _{off}	—	750	—	ns	I _{B1} = -I _{B2} = 10mA

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

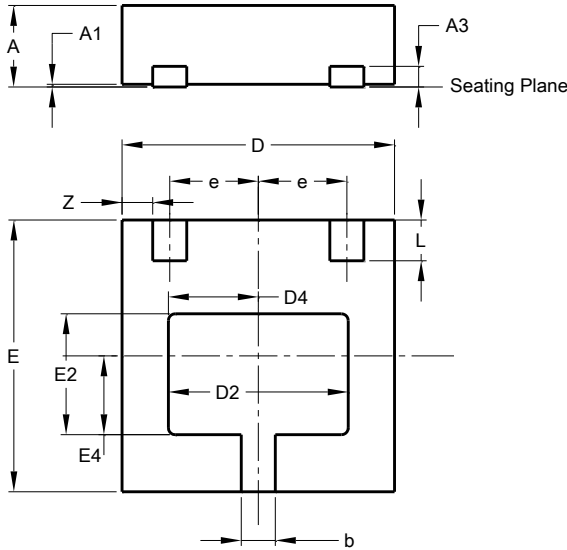
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-3 (Type B)

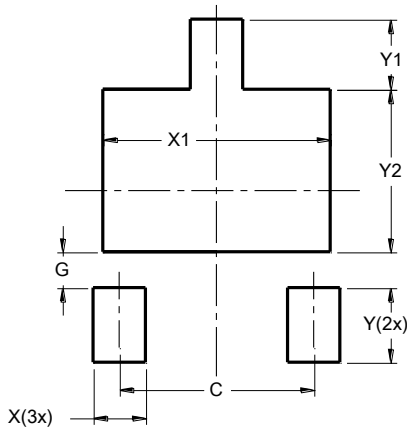


U-DFN2020-3 (Type B)			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0.00	0.05	0.02
A3	—	—	0.152
b	0.20	0.30	0.25
D	1.950	2.075	2.00
D2	1.22	1.42	1.32
D4	0.56	0.76	0.66
E	1.950	2.075	2.00
E2	0.79	0.99	0.89
E4	0.48	0.68	0.58
e	—	—	0.65
L	0.25	0.35	0.30
Z	—	—	0.225
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN2020-3 (Type B)



Dimensions	Value (in mm)
C	1.300
G	0.240
X	0.350
X1	1.520
Y	0.500
Y1	0.470
Y2	1.090

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